

## Montag, 13.01.2020 um 15:15 Uhr Ort: Seminarraum 87, Wilhelm Klemm-Straße 10

## Site-selectively generated photon emitters in atomically thin MoS<sub>2</sub>

## Dr. Julian Klein

Walter Schottky Institut and Physik Department TU München

Two-dimensional materials offer a wide range of perspectives for hosting functional and highly localized zerodimensional states, e.g. vacancy defects, that offer great potential for nano-photonic applications. The siteselective generation of such defects and the fundamental understanding of their optical and electronic properties are of particular importance for a future integration in photonic devices.

In my talk, I will demonstrate the highly local generation of individual optically active defects in a monolayer MoS<sub>2</sub> van der Waals heterostructure. [1] The result is realized by irradiating monolayer MoS<sub>2</sub> with helium ions to generate optically active defect luminescence [2] and by hBN encapsulation of the defective MoS<sub>2</sub> to greatly enhance optical quality. [3] The subsequent encapsulation reveals narrow spatially localized spectral lines that exhibit emission that is redshifted by 100 - 220 meV below the neutral 2D exciton, whereas irradiation through a fully hBN encapsulated monolayer MoS<sub>2</sub> results in background free and highly homogeneous defect emission with a FWHM of 30 meV with an energy redshift of 193 meV. [4] Individual defects are spectroscopically investigated through photoluminescence excitation spectroscopy and temperature dependent measurements. The line shape reveals a strong asymmetry resembling the interaction with LA/TA phonons. Employing the independent Boson model to our emission lines, we find that the emitters are spatially localized to a length scale of 2 nm. We attribute the emission to atomistic defects induced by the helium ion irradiation and discuss their origin in the light of scanning tunneling microscopy measurements. [5] Finally, if time permits, I will discuss recent results from defects implanted in field-switchable van der Waals devices, magneto-optical spectroscopy and measurements at sub-K temperatures.

- [1] J. Klein et al., Nature Comm. 10, 2755 (2019)
- [2] J. Klein et al., 2D Mater. 5, 1 (2017)
- [3] J. Wierzbowski and J. Klein et al., Sci. Rep. 7, 12383 (2017)
- [4] J. Klein and L. Sigl et al., to be submitted (2019)
- [5] J. Klein et al., Appl. Phys. Lett. 115, 261603 (2019)